

TLP620, TLP620-2, TLP620-4

Programmable Controllers
AC / DC-Input Module
Telecommunication

The TOSHIBA TLP620, -2 and -4 consists of a photo-transistor optically coupled to two infrared emitting diode connected in inverse parallel.

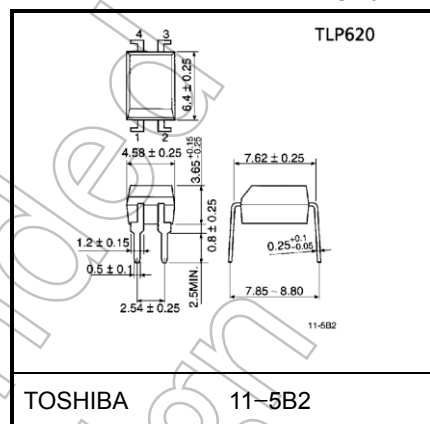
The TLP620-2 offers two isolated channels in an eight lead plastic DIP, while the TLP620-4 provides four isolated channels in a sixteen plastic DIP.

- Collector-emitter voltage: 55V (min.)
- Current transfer ratio: 50% (min.)
Rank GB: 100% (min.)
- Isolation voltage: 5000V_{rms} (min.)
- Safety Standards
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A
File No.E67349
- VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When an VDE approved type is needed, please designate the **Option(D4)**.

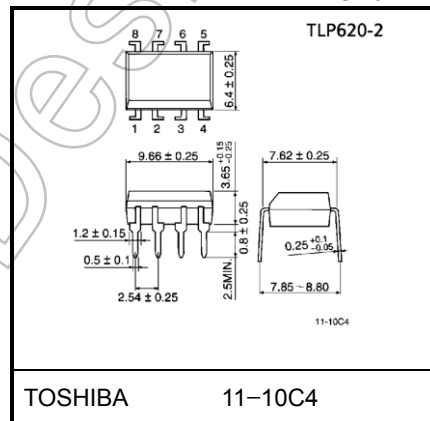
- | | 7.62 mm pitch
standard type | 10.16 mm pitch
TLP×××F type |
|----------------------|--------------------------------|--------------------------------|
| • Creepage distance | : 6.4 mm (min) | 8.0 mm (min) |
| Clearance | : 6.4 mm (min) | 8.0 mm (min) |
| Insulation thickness | : 0.4 mm (min) | 0.4 mm (min) |

Unit: mm



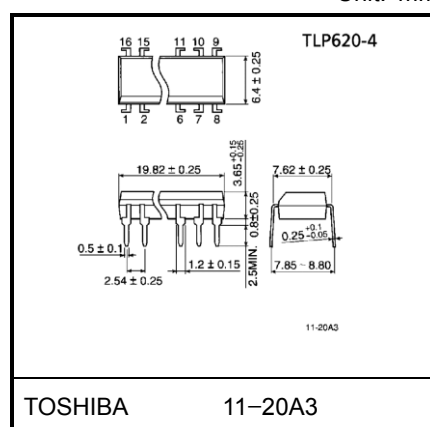
Weight: 0.26 g (typ.)

Unit: mm



Weight: 0.54 g (typ.)

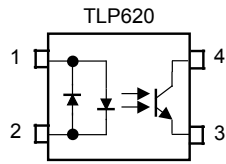
Unit: mm



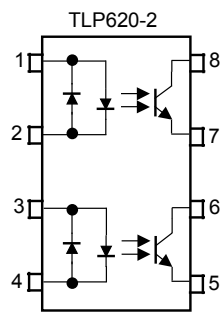
Weight: 1.1 g (typ.)

Start of commercial production
1984-01

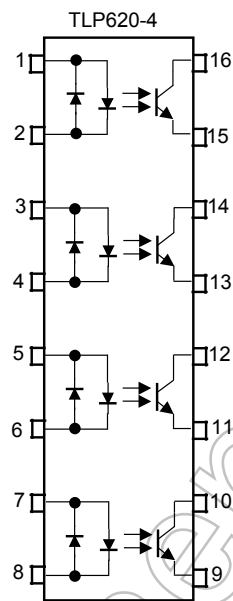
Pin Configurations (top view)



- 1 : ANODE
- CATHODE
- 2 : CATHODE
- ANODE
- 3 : EMITTER
- 4 : COLLECTOR



- 1, 3 : ANODE
- CATHODE
- 2, 4 : CATHODE
- ANODE
- 5, 7 : EMITTER
- 6, 8 : COLLECTOR



- 1, 3, 5, 7 : ANODE, CATHODE
- 2, 4, 6, 8 : CATHODE, ANODE
- 9, 11, 13, 15 : EMITTER
- 10, 12, 14, 16 : COLLECTOR

Not Recommended for New Design

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating		Unit
			TLP620	TLP620-2 TLP620-4	
LED	Forward current	I _F (RMS)	60	50	mA
	Forward current derating	ΔI _F / °C	-0.7 (Ta ≥ 39°C)	-0.5 (Ta ≥ 25°C)	mA / °C
	Pulse forward current	I _{FP}	± 1 (100μs pulse, 100pps)		A
	Power dissipation (1 circuit)	P _D	100	70	mW
	Power dissipation derating (1 circuit)	ΔP _D / °C	-1.2 (Ta ≥ 39°C)	-0.7 (Ta ≥ 25°C)	mW / °C
	Junction temperature	T _j	125		°C
Detector	Collector-emitter voltage	V _{CEO}	55		V
	Emitter-collector voltage	V _{ECO}	7		V
	Collector current	I _C	50		mA
	Collector power dissipation (1 circuit)	P _C	150	100	mW
	Collector power dissipation derating (1 circuit) (Ta ≥ 25°C)	ΔP _C / °C	-1.5	-1.0	mW / °C
	Junction temperature	T _j	125		°C
Storage temperature range		T _{stg}	-55~125		°C
Operating temperature range		T _{opr}	-55~100		°C
Lead soldering temperature		T _{sold}	260 (10 s)		°C
Total package power dissipation (1 circuit)		P _T	250	150	mW
Total package power dissipation derating (Ta ≥ 25°C, 1 circuit)		ΔP _T / °C	-2.5	-1.5	mW / °C
Isolation voltage (Note1)		BVs	5000 (AC, 60 s., RH ≤ 60 %)		V _{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{CC}	—	5	24	V
Forward current	I_F (RMS)	—	16	25	mA
Collector current	I_C	—	1	10	mA
Operating temperature	T_{opr}	-25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

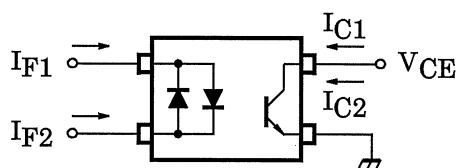
Individual Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	$I_F = \pm 10 \text{ mA}$	1.0	1.15	1.3	V
	Forward current	I_F	$V_F = \pm 0.7 \text{ V}$	—	2.5	20	μA
	Capacitance	C_T	$V = 0 \text{ V}, f = 1 \text{ MHz}$	—	60	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 0.5 \text{ mA}$	55	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR)ECO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector dark current	I_{CEO}	$V_{CE} = 24 \text{ V}$	—	10	100	nA
			$V_{CE} = 24 \text{ V}, T_a = 85^\circ\text{C}$	—	2	50	μA
Capacitance (collector to emitter)	C_{CE}	$V_{CE} = 0 \text{ V}, f = 1 \text{ MHz}$	—	10	—	pF	

Coupled Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	I_C / I_F	$I_F = \pm 5 \text{ mA}, V_{CE} = 5 \text{ V}$ Rank GB	50	—	600	%
			100	—	600	
Saturated CTR	I_C / I_F (sat)	$I_F = \pm 1 \text{ mA}, V_{CE} = 0.4 \text{ V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	V_{CE} (sat)	$I_C = 2.4 \text{ mA}, I_F = \pm 8 \text{ mA}$ $I_C = 0.2 \text{ mA}, I_F = \pm 1 \text{ mA}$ Rank GB	—	—	0.4	V
			—	0.2	—	
			—	—	0.4	
Off-state collector current	I_C (off)	$V_F = \pm 0.7 \text{ V}, V_{CE} = 24 \text{ V}$	—	1	10	μA
CTR symmetry (Note.)	I_C (ratio)	$I_C (I_F = -5 \text{ mA}) / I_C (I_F = +5 \text{ mA})$	0.33	—	3	—

Note : $I_{C(\text{ratio})} = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5\text{V})}{I_{C1}(I_F = I_{F1}, V_{CE} = 5\text{V})}$



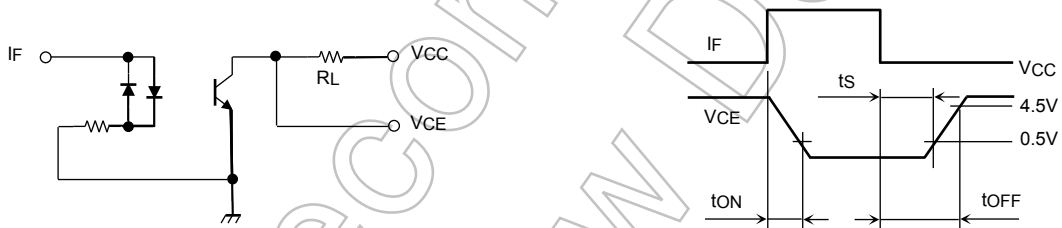
Isolation Characteristics (Ta = 25°C)

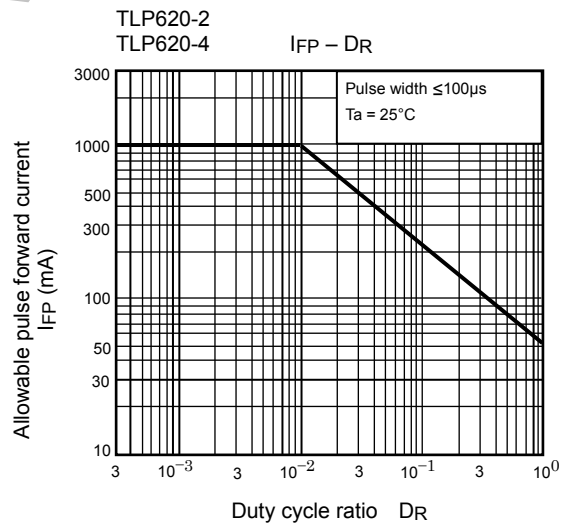
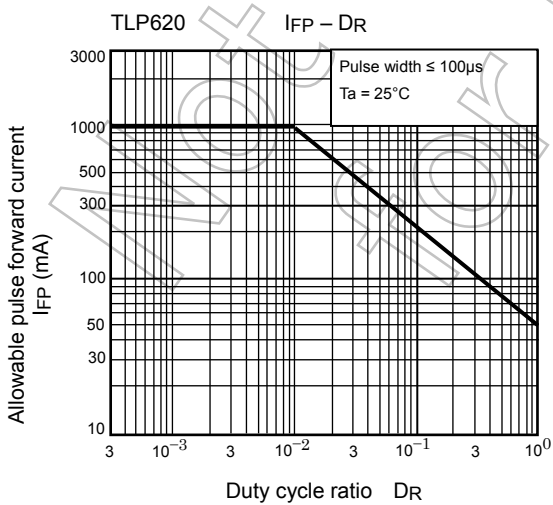
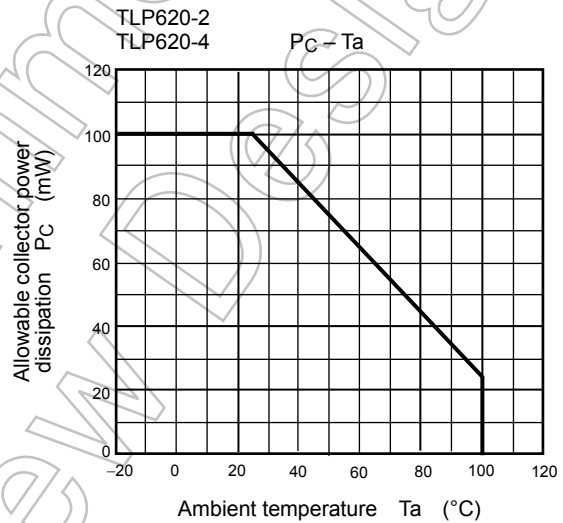
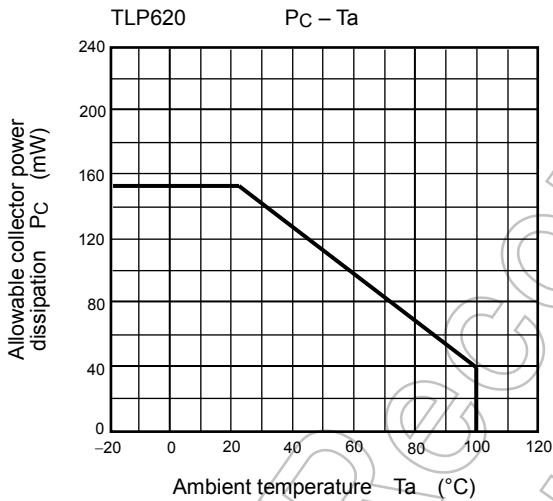
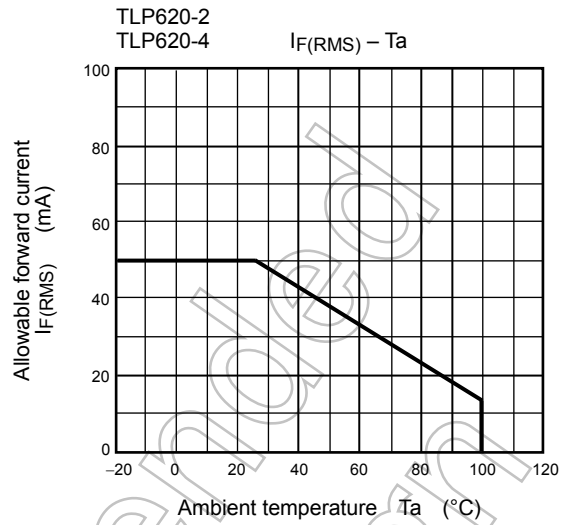
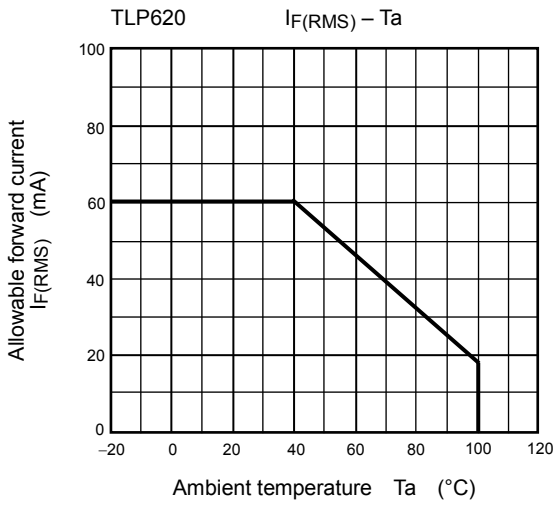
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	C _S	V _S = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60 %	1×10 ¹²	10 ¹⁴	—	Ω
Isolation voltage	BV _S	AC, 60 s	5000	—	—	V _{rms}

Switching Characteristics (Ta = 25°C)

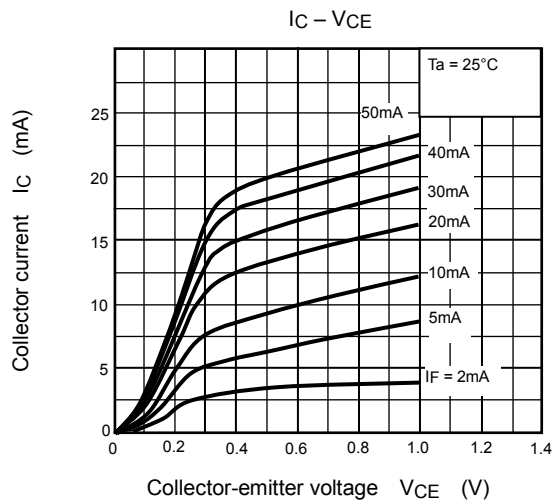
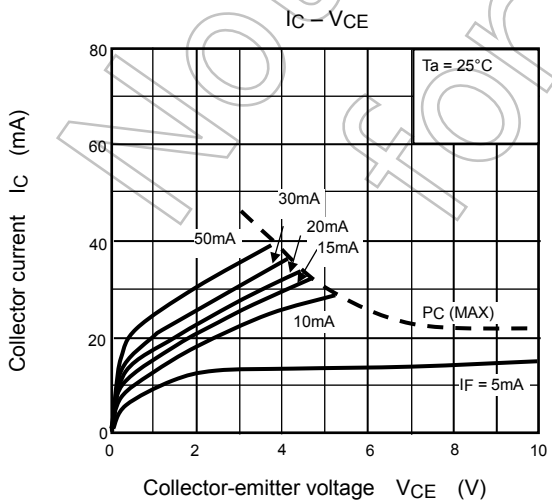
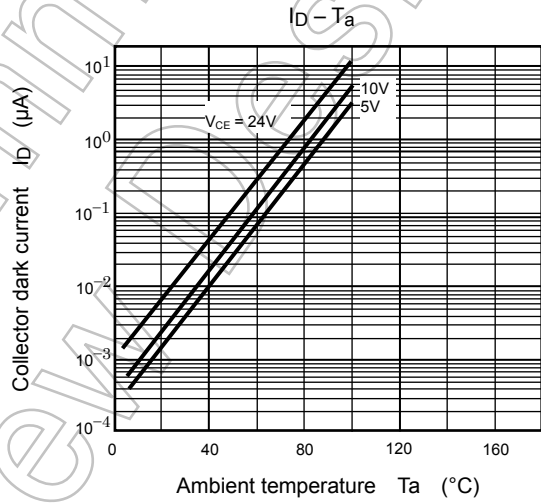
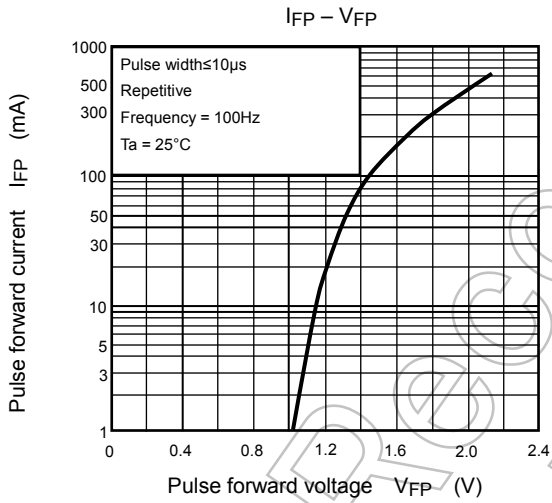
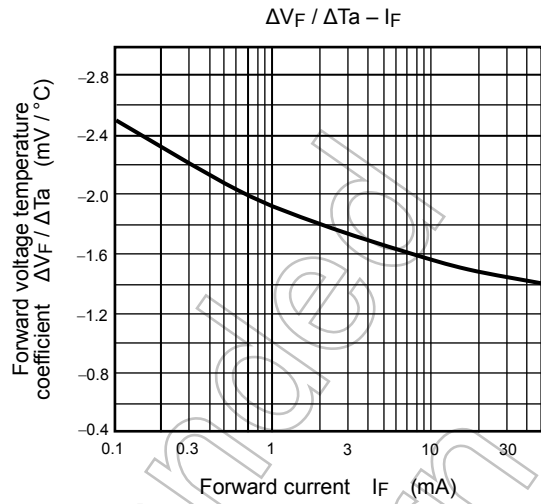
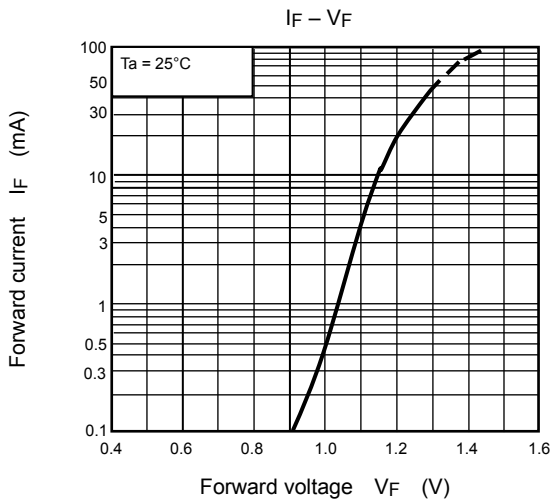
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Rise time	t _r	V _{CC} = 10 V I _C = 2 mA R _L = 100 Ω	—	2	—	μs
Fall time	t _f		—	3	—	
Turn-on time	t _{on}		—	3	—	
Turn-off time	t _{off}		—	3	—	
Turn-on time	t _{ON}	R _L = 1.9 kΩ V _{CC} = 5 V, I _F = ±16 mA (Fig.1)	—	2	—	μs
Storage time	t _s		—	15	—	
Turn-off time	t _{OFF}		—	25	—	

Fig. 1 Switching time test circuit

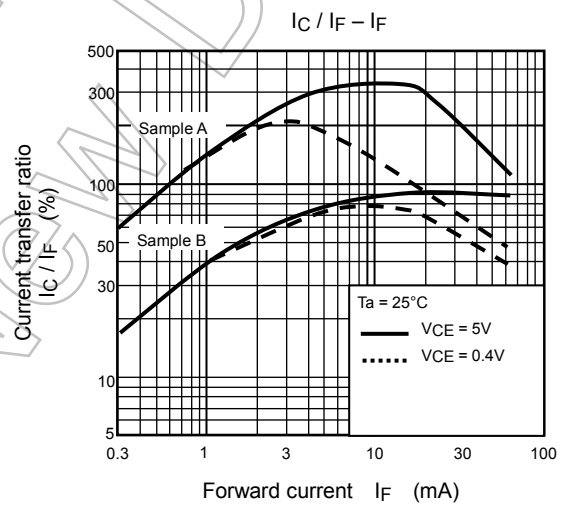
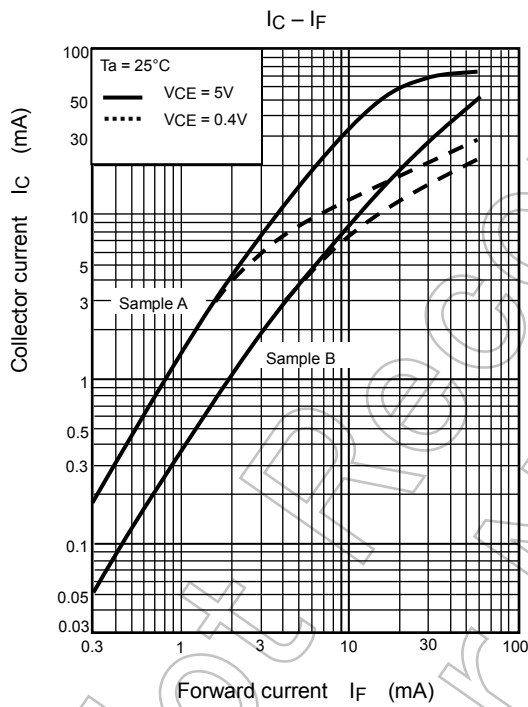
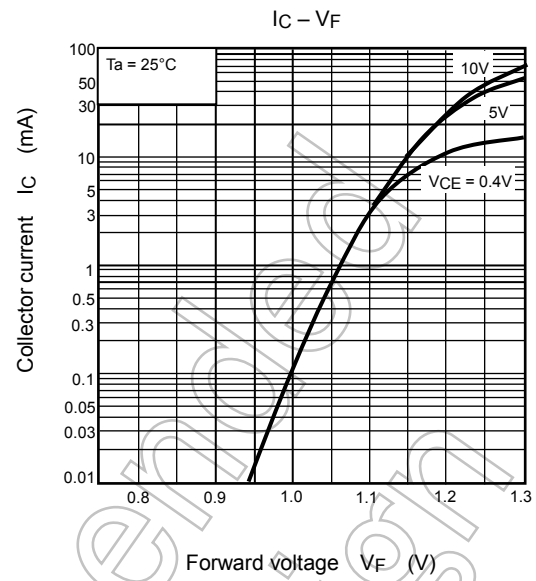
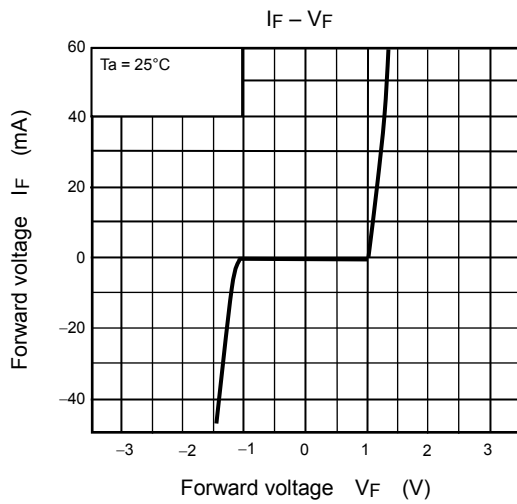




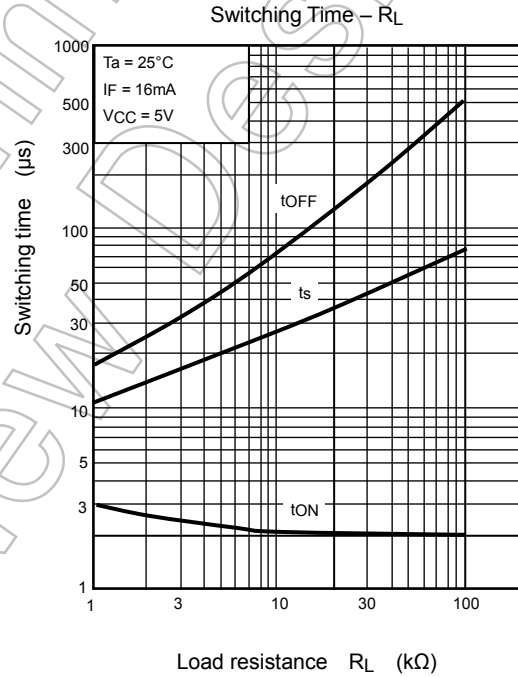
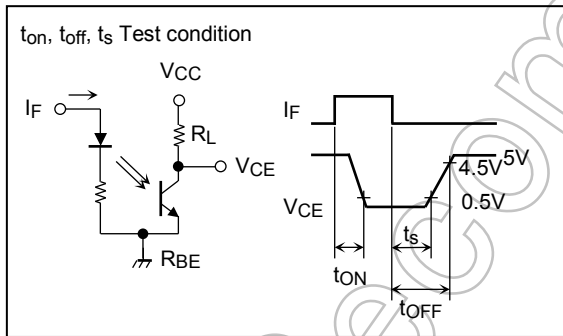
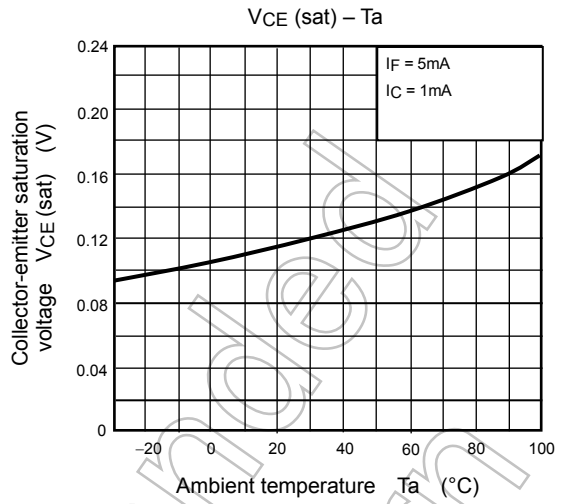
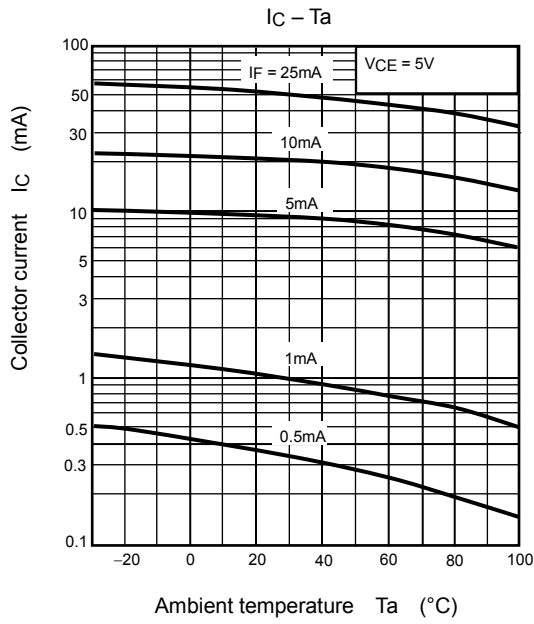
NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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